70V NPN MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

Features

- BV_{CEO} > 70V
- BV_{CBO} > 70V
- I_C = 2A High Continuous Current
- h_{FE} > 400 for High Gain @ 0.5A
- Complementary PNP Type: FZT792A
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/**

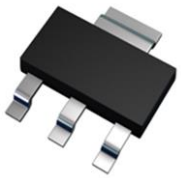
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (Approximate)

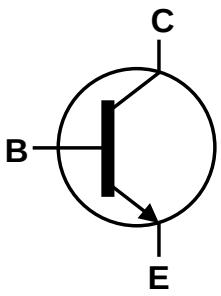
Applications

- Darlington replacements
- Relay and solenoid drivers
- DC-DC converters

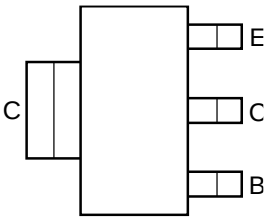
SOT223 (Type DN)



Top View



Device Symbol



Top View
Pin-Out

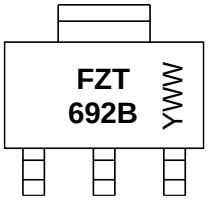
Ordering Information (Note 4)

Part Number	Compliance	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
						Qty.	Carrier
FZT692BTA	Standard	SOT223 (Type DN)	FZT692B	7	12	1,000	Reel

Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT223 (Type DN)



FZT 692B = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Last Digit of Year (ex: 2 = 2022)
WW or $\overline{WW}$ = Week Code (01 to 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	70	V
Collector-Emitter Voltage	V_{CEO}	70	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	2	A
Peak Pulse Current	I_{CM}	5	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

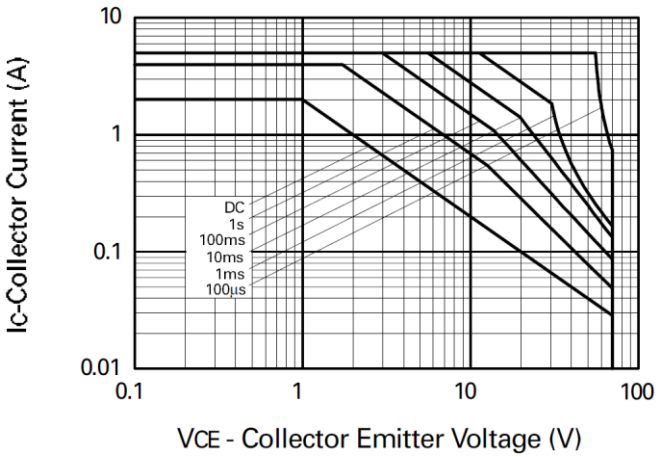
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	3.0	W
	(Note 6)		2.0	
	(Note 7)		1.6	
	(Note 8)		1.2	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	41.7	°C/W
	(Note 6)		62.5	
	(Note 7)		78.1	
	(Note 8)		104	
Thermal Resistance Junction to Lead	(Note 9)	$R_{\theta JL}$	12.9	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 10)

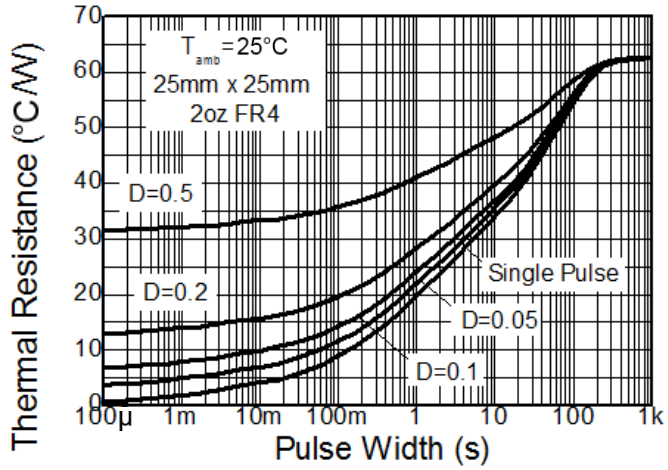
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
9. Thermal resistance from junction to solder-point (at the end of the collector lead).
10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

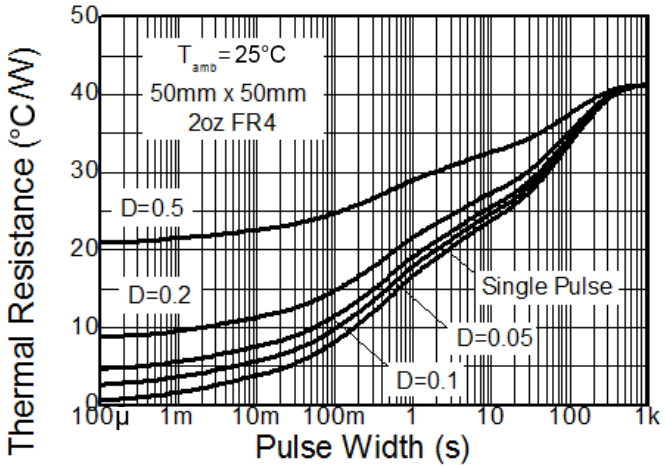
Thermal Characteristics and Derating Information



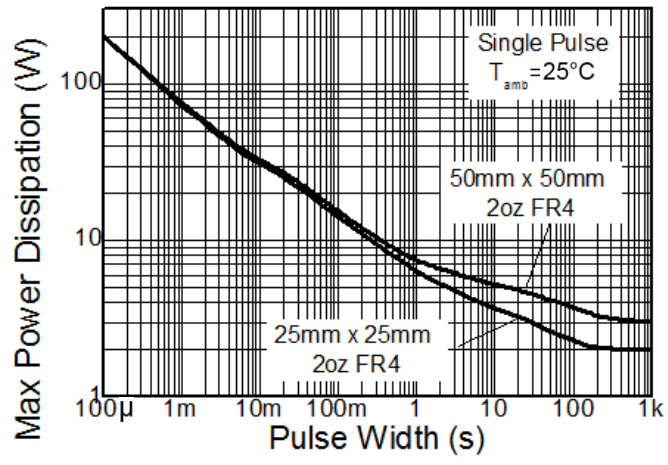
Safe Operating Area



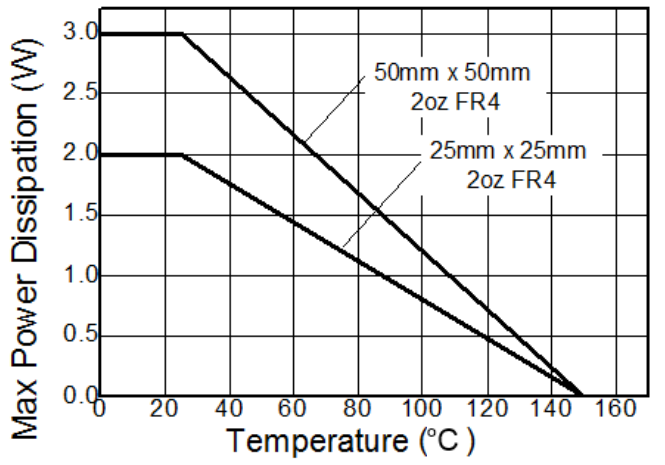
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



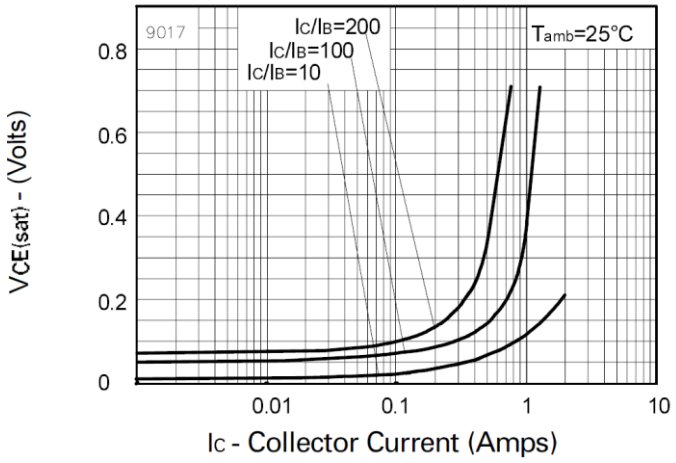
Derating Curve

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

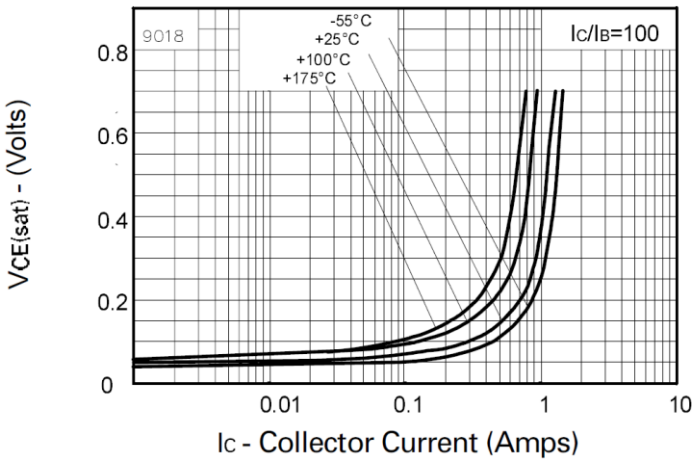
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	70	—	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage (Note 11)	BV_{CEO}	70	—	—	V	I_C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	—	—	V	I_E = 100µA
Collector-Base Cut-Off Current	I_{CBO}	—	—	50	nA	V_{CB} = 55V
Collector-Emitter Cut-Off Current	I_{CES}	—	—	50	nA	V_{CE} = 55V
Emitter Cut-Off Current	I_{EBO}	—	—	20	nA	V_{EB} = 6V
DC Current Gain (Note 11)	h_{FE}	500 400 150	— — —	— — —	—	I_C = 100mA, V_{CE} = 2V I_C = 500mA, V_{CE} = 2V I_C = 1A, V_{CE} = 2V
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(sat)}$	— — —	— — —	150 500 500	mV	I_C = 0.1A, I_B = 0.5mA I_C = 1A, I_B = 10mA I_C = 2A, I_B = 200mA
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	—	—	0.9	V	I_C = 1A, I_B = 10mA
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	—	—	0.9	V	I_C = 1A, V_{CE} = 2V
Input Capacitance	C_{ibo}	—	200	—	pF	V_{EB} = 0.5V, f = 1MHz
Output Capacitance	C_{obo}	—	12	—	pF	V_{CB} = 10V, f = 1MHz
Current Gain-Bandwidth Product	f_T	150	—	—	MHz	V_{CE} = 5V, I_C = 50mA, f = 50MHz
Turn-On Time	t_{on}	—	46	—	ns	V_{CC} = 10V, I_C = 500mA
Turn-Off Time	t_{off}	—	1440	—	ns	I_{B1} = -I_{B2} = 50mA

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

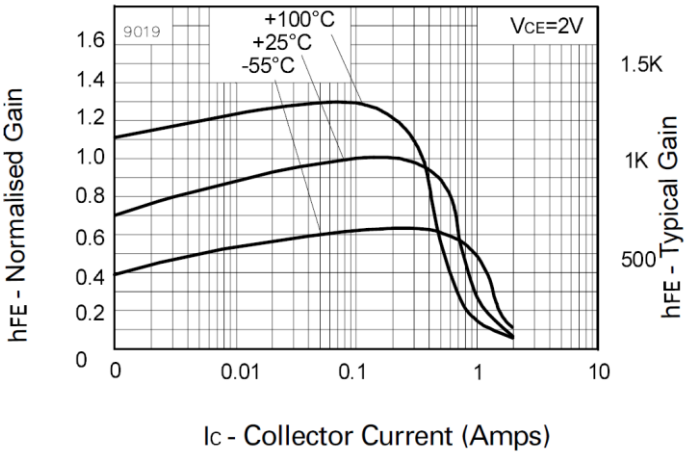
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



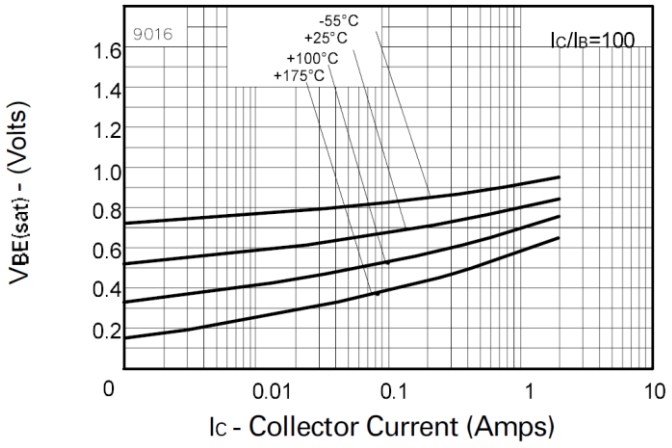
VCE(sat) v IC



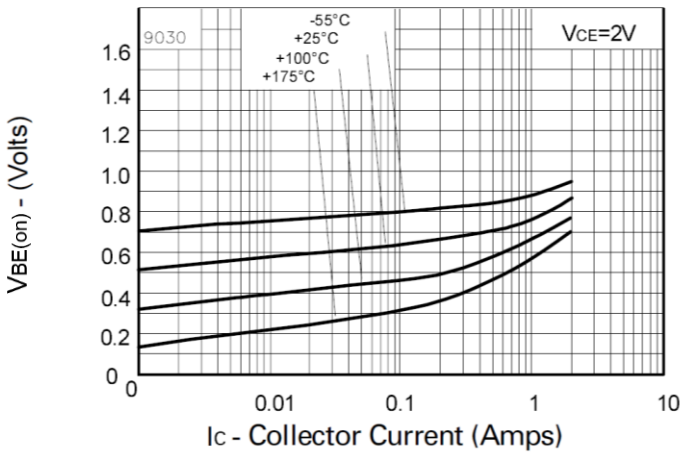
VCE(sat) v IC



hFE v IC



VBE(sat) v IC

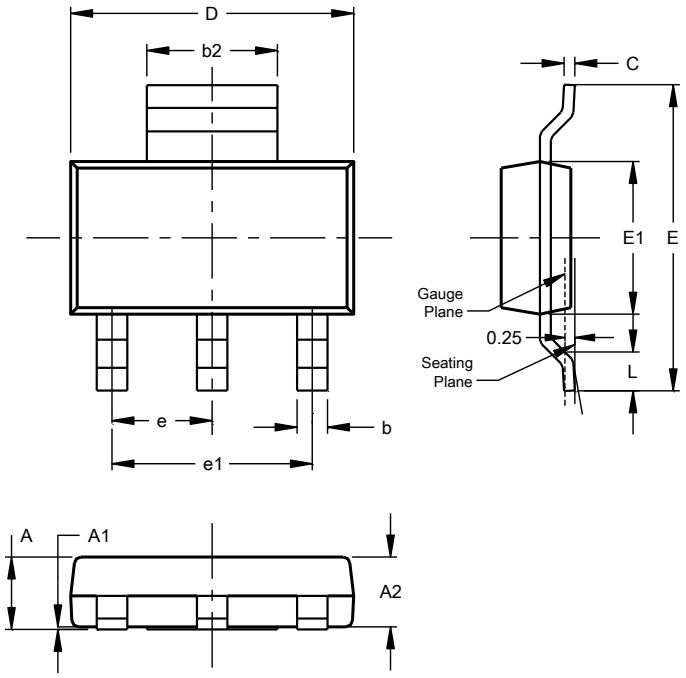


VBE(on) v IC

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

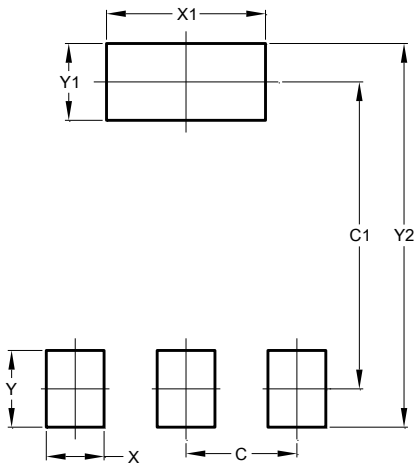


SOT223 (Type DN)			
Dim	**Min**	**Max**	**Typ**
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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